SIEMENS

Data sheet 3UG4832-1AA40



Digital monitoring relay Voltage monitoring, 22.5 mm for IO-Link 10...600 V AC/DC Overvoltage and undervoltage Hysteresis 0.1 to 300 V ON-delay time Tripping delay time 1 change-over contact, screw terminal

product brand name	SIRIUS
product designation	Voltage monitoring relay with digital setting
product type designation	3UG4
General technical data	
product function	Voltage monitoring relay
design of the display	LCD
insulation voltage for overvoltage category III according to IEC 60664	
 with degree of pollution 2 rated value 	690 V
degree of pollution	2
type of voltage	
 for monitoring 	AC/DC
 of the control supply voltage 	DC
surge voltage resistance rated value	6 kV
maximum permissible voltage for protective separation	
 between control and auxiliary circuit 	690 V
shock resistance according to IEC 60068-2-27	sinusoidal half-wave 15g / 11 ms
vibration resistance according to IEC 60068-2-6	1 6 Hz: 15 mm, 6 500 Hz: 2g
mechanical service life (operating cycles) typical	10 000 001
electrical endurance (operating cycles) at AC-15 at 230 V typical	100 000
thermal current of the switching element with contacts maximum	5 A
reference code according to IEC 81346-2	К
relative repeat accuracy	1 %
Substance Prohibitance (Date)	05/01/2012
SVHC substance name	Lead - 7439-92-1 Lead monoxide (lead oxide) - 1317-36-8
Weight	0.147 kg
Product Function	
product function	
 undervoltage detection 	Yes
overvoltage detection	Yes
 overvoltage detection 1 phase 	Yes
 overvoltage detection 3 phase 	No
overvoltage detection DC	Yes
 undervoltage detection 1 phase 	Yes
 undervoltage detection 3 phases 	No
 undervoltage detection DC 	Yes
undervoltage detection DCvoltage window recognition 1 phase	Yes Yes

 voltage window recognition DC 	Yes
 adjustable open/closed-circuit current principle 	Yes
external reset	Yes
auto-RESET	Yes
Control circuit/ Control	
control supply voltage at DC rated value	24 V
operating range factor control supply voltage rated value at DC	
• initial value	0.75
full-scale value	1.25
Measuring circuit	
measurable line frequency	500 40 Hz
measurable voltage at AC	10 600 V
measurable voltage at DC	10 600 V
adjustable response delay time	
when starting	0 999.9 s
with lower or upper limit violation	0 999.9 s
accuracy of digital display	+/-1 digit
relative temperature-related measurement deviation	0.1 %
Precision	
relative metering precision	5 %
Communication/ Protocol	
protocol is supported IO-Link protocol	Yes
IO-Link transfer rate	COM2 (38,4 kBaud)
point-to-point cycle time between master and IO-Link	10 ms
device minimum	
type of voltage supply via input/output link master	Yes
data volume	4 byto
 of the address range of the inputs with cyclical transfer total 	4 byte
 of the address range of the outputs with cyclical transfer total 	2 byte
Auxiliary circuit	
number of NC contacts delayed switching	0
number of NO contacts delayed switching	0
number of CO contacts delayed switching	1
operating frequency with 3RT2 contactor maximum	5 000 1/h
Main circuit	
mani circuit	
number of poles for main current circuit	1
	1 200 mA
number of poles for main current circuit ampacity of the semiconductor output in SIO mode operational current at 17 V minimum	200 mA 10 mA
number of poles for main current circuit ampacity of the semiconductor output in SIO mode operational current at 17 V minimum continuous current of the DIAZED fuse link of the output	200 mA
number of poles for main current circuit ampacity of the semiconductor output in SIO mode operational current at 17 V minimum continuous current of the DIAZED fuse link of the output relay	200 mA 10 mA
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number of poles for main current circuit ampacity of the semiconductor output in SIO mode operational current at 17 V minimum continuous current of the DIAZED fuse link of the output relay Electromagnetic compatibility conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5	200 mA 10 mA 4 A 2 kV 2 kV 1 kV
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number of poles for main current circuit ampacity of the semiconductor output in SIO mode operational current at 17 V minimum continuous current of the DIAZED fuse link of the output relay Electromagnetic compatibility conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2	200 mA 10 mA 4 A 2 kV 2 kV 1 kV
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number of poles for main current circuit ampacity of the semiconductor output in SIO mode operational current at 17 V minimum continuous current of the DIAZED fuse link of the output relay Electromagnetic compatibility conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 Galvanic isolation design of the electrical isolation	200 mA 10 mA 4 A 2 kV 2 kV 1 kV
number of poles for main current circuit ampacity of the semiconductor output in SIO mode operational current at 17 V minimum continuous current of the DIAZED fuse link of the output relay Electromagnetic compatibility conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 Galvanic isolation design of the electrical isolation galvanic isolation	200 mA 10 mA 4 A 2 kV 2 kV 1 kV 10 V/m 6 kV contact discharge / 8 kV air discharge
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number of poles for main current circuit ampacity of the semiconductor output in SIO mode operational current at 17 V minimum continuous current of the DIAZED fuse link of the output relay Electromagnetic compatibility conducted interference • due to burst according to IEC 61000-4-4 • due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 Galvanic isolation design of the electrical isolation galvanic isolation • between input and output • between the voltage supply and other circuits	200 mA 10 mA 4 A 2 kV 2 kV 1 kV 10 V/m 6 kV contact discharge / 8 kV air discharge Protective separation Yes
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type of connectable conductor cross-sections	
• solid	1x (0.5 4.0 mm²), 2x (0.5 2.5 mm²)
 finely stranded with core end processing 	1x (0.5 2.5 mm2), 2x (0.5 1.5 mm2)
for AWG cables solid	2x (20 14)
 for AWG cables stranded 	2x (20 14)
connectable conductor cross-section	
• solid	0.5 4 mm²
 finely stranded with core end processing 	0.5 2.5 mm²
AWG number as coded connectable conductor cross section	
• solid	20 14
• stranded	20 14
tightening torque with screw-type terminals	1.2 0.8 N·m
Installation/ mounting/ dimensions	
mounting position	any
fastening method	snap-on mounting
height	92 mm
width	22.5 mm
depth	91 mm
required spacing	
with side-by-side mounting	
— forwards	0 mm
— backwards	0 mm
— upwards	0 mm
— downwards	0 mm
— at the side	0 mm
 for grounded parts 	
— forwards	0 mm
— backwards	0 mm
— upwards	0 mm
— at the side	0 mm
— downwards	0 mm
• for live parts	0
— forwards	0 mm
— backwards	0 mm
— upwards	0 mm
— at the side	0 mm
Ambient conditions	2,000
installation altitude at height above sea level maximum	2 000 m
ambient temperature	25 ±60 °C
during operation during storage	-25 +60 °C 8540 °C
during storageduring transport	8540 °C
Approvals Certificates	00 -1 0 C
General Product Approval	



Confirmation



Manufacturer Declaration





General Product Approval

EMV

Test Certificates

Marine / Shipping





<u>KC</u>

Type Test Certificates/Test Report

Special Test Certificate



other Railway Environment

Further information

Information on the packaging

https://support.industry.siemens.com/cs/ww/en/view/109813875

Information- and Downloadcenter (Catalogs, Brochures,...)

https://www.siemens.com/ic10

Industry Mall (Online ordering system)

https://mall.industry.siemens.com/mall/en/en/Catalog/product?mlfb=3UG4832-1AA40

Cax online generator

http://support.automation.siemens.com/WW/CAXorder/default.aspx?lang=en&mlfb=3UG4832-1AA40

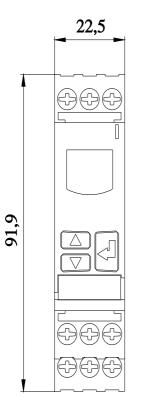
Service&Support (Manuals, Certificates, Characteristics, FAQs,...) https://support.industry.siemens.com/cs/ww/en/ps/3UG4832-1AA40

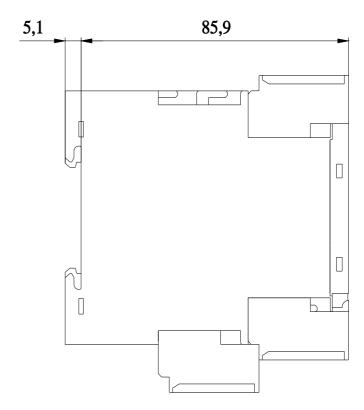
Image database (product images, 2D dimension drawings, 3D models, device circuit diagrams, EPLAN macros, ...)

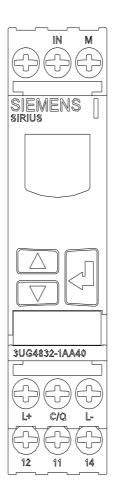
http://www.automation.siemens.com/bilddb/cax_de.aspx?mlfb=3UG4832-1AA40&lang=en

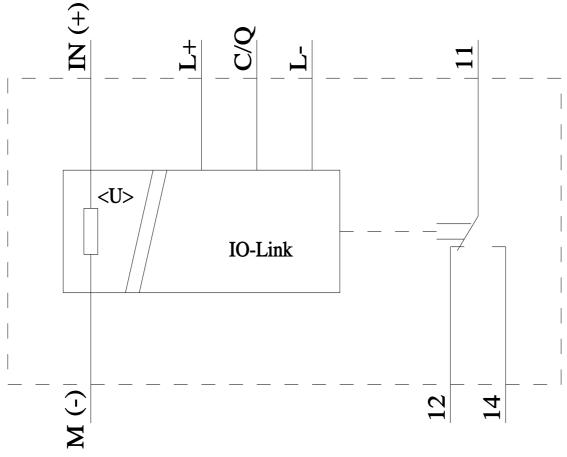
Characteristic: Derating

https://support.industry.siemens.com/cs/ww/en/ps/3UG4832-1AA40/manual









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